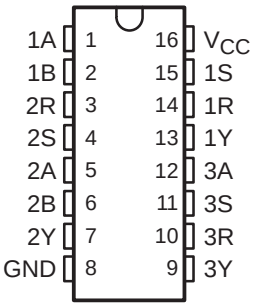
SLLS058B – SEPTEMBER 1973 – REVISED MAY 1995

- **Meets or Exceeds the Requirements of IBM™ System 360 Input/Output Interface Specification**
- **Operates From Single 5-V Supply**
- **TTL Compatible**
- **Built-In Input Threshold Hysteresis**
- **High Speed . . . Typical Propagation Delay Time = 20 ns**
- **Independent Channel Strobes**
- **Input Gating Increases Application Flexibility**
- **Designed for Use With Dual Line Driver SN75123**
- **Designed to Be Interchangeable With Signetics N8T24**

D OR N PACKAGE
(TOP VIEW)



description

The SN75124 triple line receiver is specifically designed to meet the input/output interface specifications for IBM System 360. It is also compatible with standard TTL logic and supply voltage levels.

The SN75124 has receiver inputs with built-in hysteresis to provide increased noise margin for single-ended systems. An open line affects the receiver input as does a low-level input voltage, and the receiver input can withstand a level of –0.15 V with power on or off. The other inputs are in TTL configuration. The S input must be high to enable the receiver input. Two of the line receivers have A and B inputs that, if both are high, hold the output low. The third receiver has only an A input that, if high, holds the output low.

See the SN751730 for new IBM 360/370 interface designs.

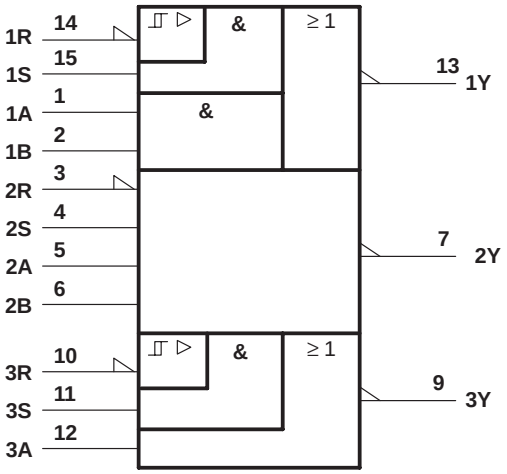
The SN75124 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE

INPUTS				OUTPUT
A	B†	R	S	Y
H	H	X	X	L
X	X	L	H	L
L	X	H	X	H
L	X	X	L	H
X	L	H	X	H
X	L	X	L	H

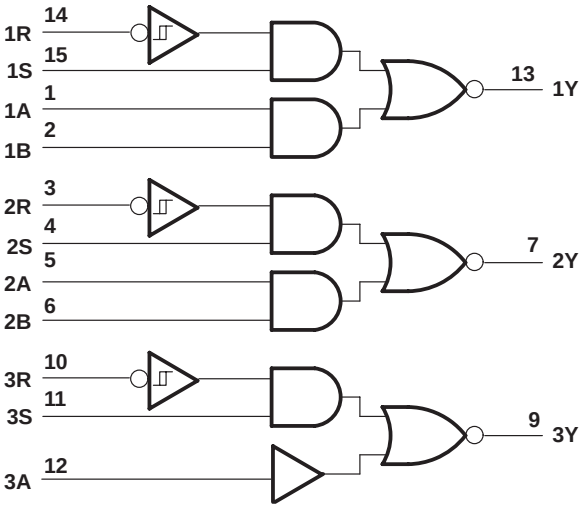
† B input and last two lines of the function table are applicable to receivers 1 and 2 only.

logic symbol†

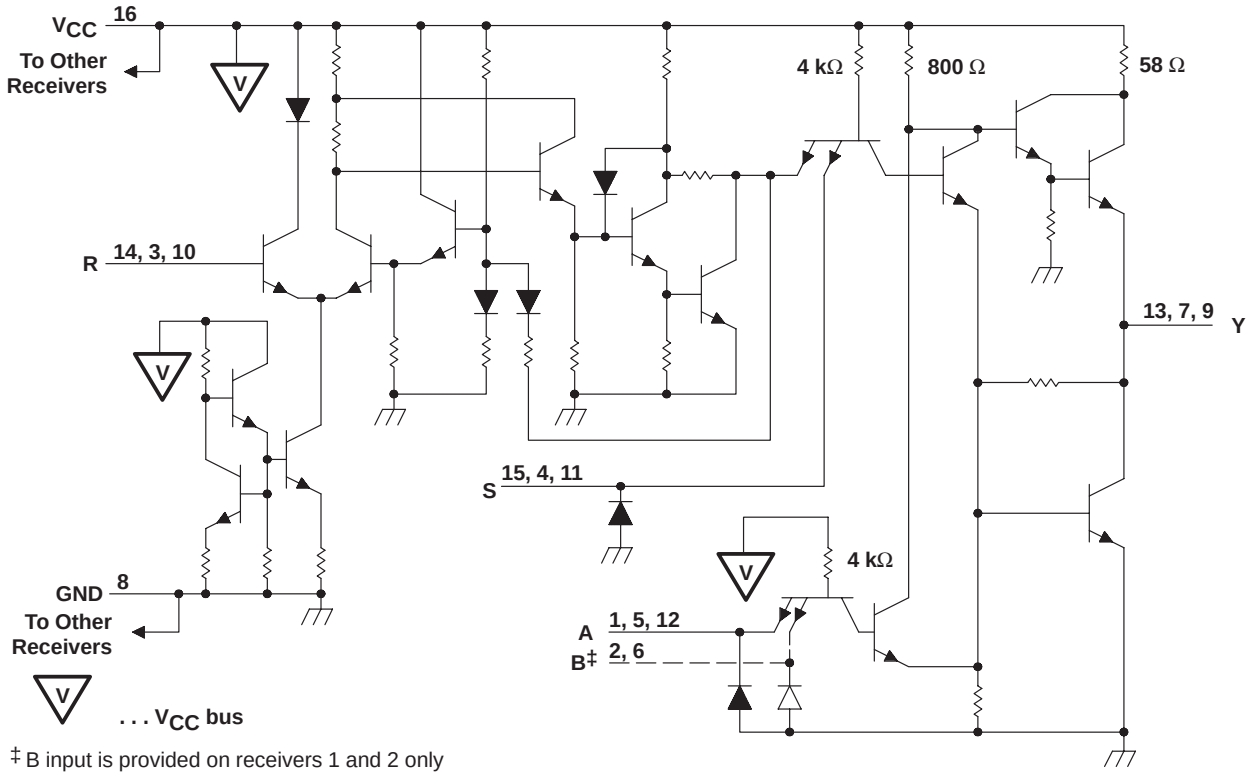


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



schematic (each receiver)



‡ B input is provided on receivers 1 and 2 only
Resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} (see Note 1) . . . . . 7 V
Input voltage, V_I: R input with V_{CC} applied . . . . . 7 V
R input with V_{CC} not applied . . . . . 6 V
A, B, or S input . . . . . 5.5 V
Output voltage, V_O . . . . . 7 V
Output current, I_O . . . . . ±100 mA
Continuous total dissipation . . . . . See Dissipation Rating Table
Operating free-air temperature range, T_A . . . . . 0°C to 70°C
Storage temperature range, T_{stg} . . . . . –65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds . . . . . 260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: Voltage values are with respect to network ground terminal

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 70°C$ POWER RATING
D	950 mW	7.6 mW/°C	608 mW
N	1150 mW	9.2 mW/°C	736 mW

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}		4.75	5	5.25	V
High-level input voltage, V_{IH}	A, B, or S	2			V
	R	1.7			
Low-level input voltage, V_{IL}	A, B, or S			0.8	V
	R			0.7	
High-level output current, I_{OH}				–800	µA
Low-level output current, I_{OL}				16	mA
Operating free-air temperature, T_A		0		70	°C

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{hys}	Hysteresis voltage ($V_{IT+} - V_{IT-}$)	R	V_{CC} = 5 V,	T_A = 25°C	0.2	0.5		V
V_{IK}	Input clamp voltage	A, B, or S	V_{CC} = 5 V,	I_I = –12 mA			–1.5	V
$V_{I(BR)}$	Input breakdown voltage	A, B, or S	V_{CC} = 5 V,	I_I = 10 mA	5.5			V
V_{OH}	High-level output voltage		$V_{IH} = V_{IH}$min, I_{OH} = –800 µA,	$V_{IL} = V_{IL}$max, See Note 2	2.6			V
V_{OL}	Low-level output voltage		$V_{IH} = V_{IH}$min, I_{OL} = 16 mA,	$V_{IL} = V_{IL}$max, See Note 2			0.4	V
I_I	Input current at maximum input voltage	R	V_I = 7 V				5	mA
			V_I = 6 V,	V_{CC} = 0			5	
I_{IH}	High-level input current	A, B, or S	V_I = 4.5 V				40	µA
		R	V_I = 3.11 V				170	
I_{IL}	Low-level input current	A, B, or S	V_I = 0.4 V,	V_{IR} = 0.8 V	–0.1		–1.6	mA
I_{OS}	Short-circuit output current†				–50		–100	mA
I_{CC}	Supply current		All inputs = 0.8 V				72	mA
			All inputs = 2 V				100	

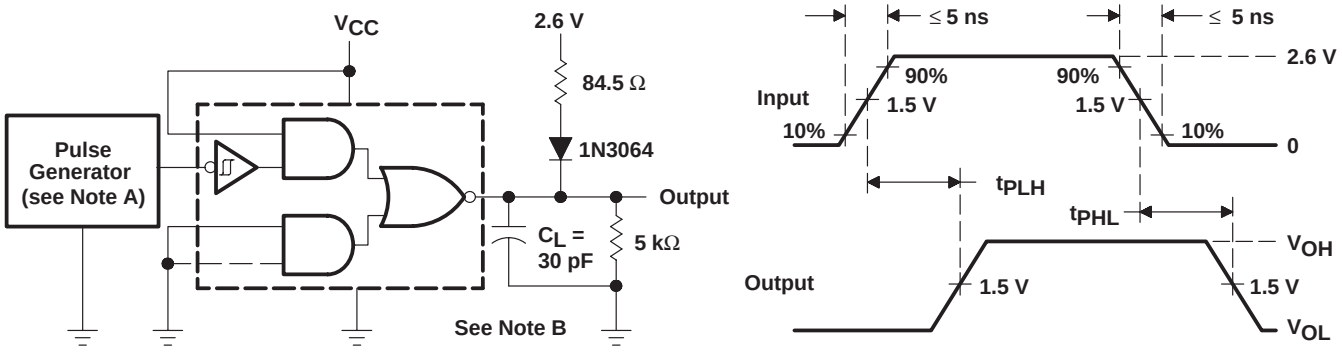
† Not more than one output should be shorted at a time, and duration of the short circuit should not exceed one second.

NOTE 2: The output voltage and current limits are characterized for any appropriate combination of high and low inputs specified by the function table for the desired output.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output from R input	See Figure 1		20	30	ns
t_{PHL}	Propagation delay time, high-to-low-level output from R input			20	30	

PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT VOLTAGE WAVEFORMS

NOTES: A. The pulse generator has the following characteristics: $Z_O \approx 50\ \Omega$, PRR ≤ 5 MHz, duty cycle = 50%.
B. C_L includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS

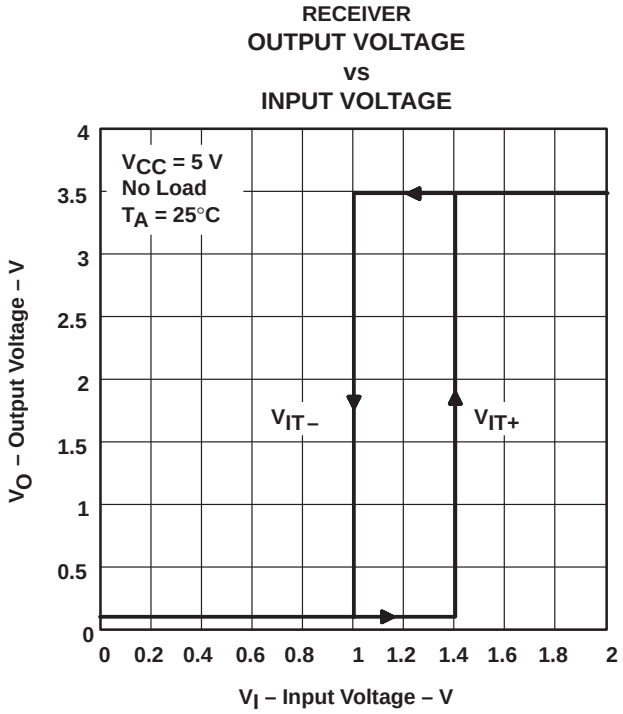


Figure 2

APPLICATION INFORMATION

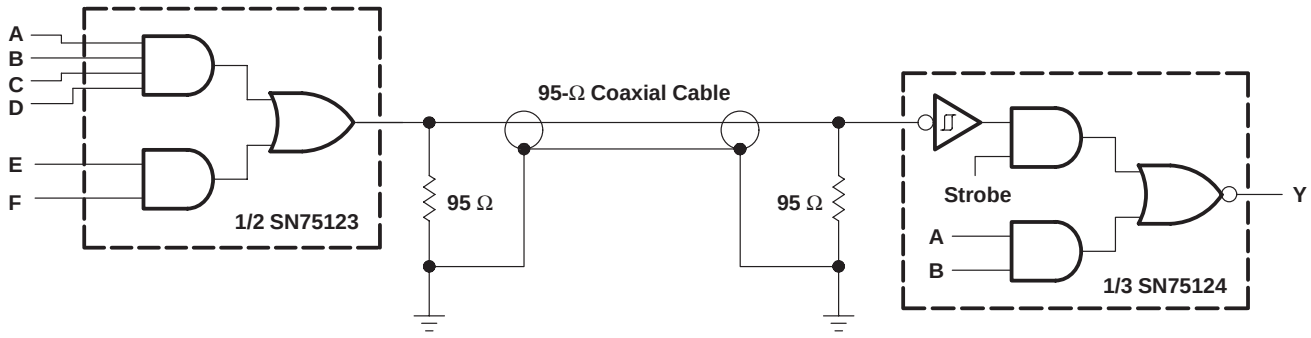


Figure 3. Unbalanced Line Communication Using SN75123 and SN75124

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